DIGITRON SEMICONDUCTORS

1N6373 - 1N6389

1500 WATT LOW CLAMPING FACTOR

TRANSIENT VOLTAGE SUPPRESSOR

- Unidirectional and bidirectional TVS series for thru-hole mounting
- Suppresses transients up to 1500 watts @ 10/1000 µs
- $t_{clamping}$ (0 volts to $V_{(BR)}$ min):
 - Unidirectional Less than 100 pico seconds
 - Bidirectional Less than 5 nano seconds
- Working voltage (V_{WM}) range 5 V to 45 V
- Low clamping factor (ratio of actual $V_C/V_{BR})\colon$ 1.33 @ full rated power and 1.20 @ 50% rated power
- Economical plastic encapsulated TVS for thru-hole mount
- Surface mount equivalent packages also available
- Available Non-RoHS (standard) or RoHS compliant (add PBF suffix)
- Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.

MAXIMUM RATINGS

| 1500 Watts for 10/1000 μs with repetition rate of 0.01% or less* at lead temperature (T _L) 25°C (See figures 1, 2, & 4) | | | |
|---|--|--|--|
| Operating and Storage Temperature: -65°C to +150°C | | | |
| Thermal Resistance: | 22°C/W junction to lead at $3/2$ from body or 82°C/W junction to ambient when mounted on FR4 PC board with 4 mm ² copper pads and track width 1 mm, length 25mm | | |
| Steady State Power Dissipation:*: | 5 watts at $T_L \le 40$ °C, or 1.52 watts at $T_A = 25$ °C when mounted on FR4 PC board described for thermal resistance | | |
| Solder Temperatures: | 260°C for 10 s (maximum) | | |

* TVS devices are not typically used for dc power dissipation and are instead operated at or less than their rated standoff voltage (V_{WM}) except for transients that briefly drive the device into avalanche breakdown (V_{BR} to V_C region).

ELECTRICAL CHARACTERISTICS @ 25°C (Unidirectional)

| Part Number | Direction | Stand-Off Voltage (Note 1) | Maximum Reverse Leakage @ V _{WM} | Minimum* Breakdown Voltage @ 1.0 mA | Maximum Clamping Voltage (Fig. 2) I _{PP1} = 1A | Maximum Clamping Voltage (Fig. 2) @ IPP2 = 10A | Maximum Peak Pulse Current |
|----------------|----------------|----------------------------------|--|--|---|---|----------------------------------|
| | | V _{WM} | ID | V (BR) (min) | Vc | Vc | I _{PP3} |
| | | VOLTS | μA | VOLTS | VOLTS | VOLTS | Α |
| 1N6373 | Unidirectional | 5.0 | 300 | 6.0 | 7.1 | 7.5 | 160 |
| 1N6374 | Unidirectional | 8.0 | 25 | 9.4 | 11.3 | 11.5 | 100 |
| 1N6375 | Unidirectional | 10.0 | 2 | 11.7 | 13.7 | 14.1 | 90 |
| 1N6376 | Unidirectional | 12.0 | 2 | 14.1 | 16.1 | 16.5 | 70 |
| 1N6377 | Unidirectional | 15.0 | 2 | 17.6 | 20.1 | 20.6 | 60 |
| 1N6378 | Unidirectional | 18.0 | 2 | 21.2 | 24.2 | 25.2 | 50 |
| 1N6379 | Unidirectional | 22.0 | 2 | 25.9 | 29.8 | 32.0 | 40 |
| 1N6380 | Unidirectional | 36.0 | 2 | 42.4 | 50.6 | 54.3 | 23 |
| 1N6381 | Unidirectional | 45.0 | 2 | 52.9 | 63.3 | 70.0 | 19 |
| 1N6382 | Bidirectional | 8.0 | 25 | 9.4 | 11.4 | 11.6 | 100 |
| 1N6383 | Bidirectional | 10.0 | 2 | 11.7 | 14.1 | 14.5 | 90 |
| 1N6384 | Bidirectional | 12.0 | 2 | 14.1 | 16.7 | 17.1 | 70 |
| 1N6385 | Bidirectional | 15.0 | 2 | 17.6 | 20.8 | 21.4 | 60 |
| 1N6386 | Bidirectional | 18.0 | 2 | 21.2 | 24.8 | 25.5 | 50 |

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ELECTRICAL CHARACTERISTICS @ 25°C (Bidirectional)

| Part Number | Direction | Stand-Off Voltage (Note 1) | Maximum Reverse Leakage | Minimum* Breakdown Voltage @ 1.0 mA | Maximum Clamping Voltage I _{PP1} = 1A | Maximum Clamping Voltage @ I _{PP2} = 10A | Maximum Peak Pulse Current |
|----------------|---------------|----------------------------------|-------------------------------|--|---|--|----------------------------------|
| | | V _{WM} | I _D | V _{(BR) (min)} | Vc | Vc | I _{PP3} |
| | | VOLTS | μA | VOLTS | VOLTS | VOLTS | Α |
| 1N6387 | Bidirectional | 22.0 | 2 | 25.9 | 30.8 | 32.0 | 40 |
| 1N6388 | Bidirectional | 36.0 | 2 | 42.4 | 50.6 | 54.3 | 23 |
| 1N6389 | Bidirectional | 45.0 | 2 | 52.9 | 63.3 | 70.0 | 19 |

Note 1: TVS devices are normally selected according to the reverse "Stand Off Voltage" (V_{WM}) which should be equal to or greater than dc or continuous peak operating voltage level.

• For bidirectional parts, add suffix C at end of the part number.

* The minimum breakdown voltage as shown takes into consideration the ±1 volt tolerance normally specified for power supply regulation on most integrated circuit manufacturers data sheets. Similar devices are available with reduced clamping voltages where tighter regulated power supply voltages are employed.



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FIGURE 5 Typical Capacitance vs. Breakdown Voltage (Bidirectional Types)

MECHANICAL CHARACTERISTICS

| Case: | Plastic, DO-201 | | |
|-----------|-----------------|--|--|
| Marking: | Alpha-Numeric | | |
| Polarity: | Cathode band | | |



| | Dimensions | | | | |
|----|------------|-------|-------------|-------|--|
| | Inc | hes | Millimeters | | |
| | Min | Max | Min | Max | |
| BD | 0.190 | 0.205 | 4.826 | 5.207 | |
| BL | 0.360 | 0.375 | 9.146 | 9.527 | |
| LD | 0.038 | 0.042 | 0.958 | 1.074 | |
| LL | 1.100 | - | 27.900 | - | |